## NSN 5961-00-432-1455

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-432-1455 **Inclosure Material:** Ceramic **Overall Length:** 0.717 inches **Overall Diameter:** 0.190 inches **End Application:** Radio set an/grc-144 **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 0.25 amperes source cutoff current preset **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 binding post Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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